

June 2007

# BSP51

# **NPN Darlington Transistor**

This device is designed for applications requiring extremly high current gain at collector currents to 500mA. Sourced from process 03.



1. Base 2. Collector 3. Emitter

# Absolute Maximum Ratings ${}^{\star}T_a = 25^{\circ}C$ unless otherwise noted

| Symbol                           | Parameter                                 | Value              | Units |
|----------------------------------|---|--------------------|-------|
| V <sub>CES</sub>                 | Collector-Emitter Voltage                 | 80                 | V     |
| V <sub>CBO</sub>                 | Collector-Base Voltage                    | 90                 | V     |
| $V_{EBO}$                        | Emitter-Base Voltage                      | 5.0                | V     |
| I <sub>C</sub>                   | Collector Current (Continuous)            | 500                | mA    |
| T <sub>J.</sub> T <sub>STG</sub> | Junction Temperature, Storage Temperature | -55 ~ <b>+</b> 150 | °C    |

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Symbol

# Electrical Characteristics \* T<sub>a</sub> = 25°C unless otherwise noted **Parameter**

| Symbol                | Parameter                        | Test Condition MIN                          |     | MAX | Units |
|-----------------------|----------------------------------|---|-----|-----|-------|
| Off Charac            | teristics                        |   |     |     |       |
| V <sub>(BR)</sub> CBO | Collector-Base Breakdown Voltage | Ic = 100 μA, Iε = 0                         | 90  |     | V     |
| V <sub>(BR)EBO</sub>  | Emitter-Base Breakdown Voltage   | Iε = 10 μA, Ic = 0                          | 5.0 |     | V     |
| Ices                  | Collector Cutoff Current         | Vce = 80 V, IBE = 0                         |     | 10  | μΑ    |
| <b>І</b> ЕВО          | Emitter Cutoff Current           | V <sub>EB</sub> = 4.0 V, I <sub>C</sub> = 0 |     | 10  | μΑ    |
|                       |                                  | •   | •   | •   | •     |

## On Characteristics

| hfE                   | DC Current Gain                        | Ic = 150 mA, VcE = 10 V<br>Ic = 500 mA, VcE = 10 V | 1000<br>2000 |     |   |
|-----------------------|--|--|--------------|-----|---|
| VcE(sat)              | Collector-Emitter Saturation Voltage * | Ic = 500 mA, I <sub>B</sub> = 0.5 mA               |              | 1.3 | V |
| V <sub>BE</sub> (sat) | Base-Emitter Saturation Voltage *      | Ic = 500 mA, I <sub>B</sub> = 0.5 mA               |              | 1.9 | V |

<sup>\*</sup> Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%

<sup>1)</sup> These ratings are based on a maximum junction temperature of 150 degrees C.

<sup>2)</sup> These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# Thermal Characteristics ${}^{\star}T_a = 25^{\circ}C$ unless otherwise noted

| Symbol        | Characteristic                          | Max  | Units |
|---------------|---|------|-------|
| Po            | Total Device Dissipation                | 1000 | mW    |
|               | Derate above 25°                        | 8.0  | mW/°C |
| R $\Theta$ JA | Thermal Resistance, Junction to Ambient | 125  | °C/W  |

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06".





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|---------|-----------------|--------------------|----------|--------------|-------|----------------|--|
| BSP51   | Full Production | Full<br>Production | \$0.158  | SOT-223      | 4     | TAPE REEL      | Line 1: <b>\$Y</b> (Fairchild logo)<br>& <b>Z</b> (Asm. Plant Code)<br>& <b>3</b> (3-Digit Date Code)<br>Line 2: BSP51 |

<sup>\*</sup> Fairchild 1,000 piece Budgetary Pricing

<sup>\*\*</sup> A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples



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